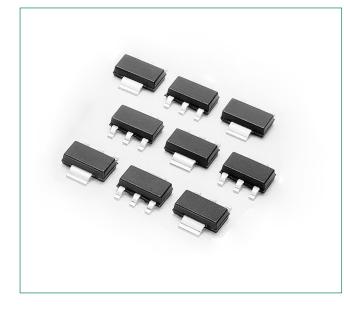


NYC222, NYC226, NYC228



Description

Designed and tested for repetitive peak operation required for CD ignition, fuel ignitors, flash circuits, motor controls and low-power switching applications.

PO

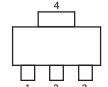
Features

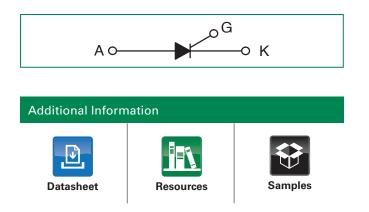
- Blocking Voltage to 600 V
- High Surge Current 15 A
- Very Low Forward "On" Voltage at High Current
- Low-Cost Surface Mount SOT–223 Package
- These are Pb-Free Devices

Functional Diagram



Pin Out







Maximum Ratings ($T_{J} = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) ($R_{GK} = I_{K}, T_{J} - 40$ to +110°C, Sine Wave, 50 to 60 Hz) NYC222 NYC228	V _{drm} , V _{rrm}	50 400 600	V
On-State RMS Current (180° Conduction Angles; T _c = 80°C)	I _{T (RMS)}	1.5	А
Average On–State Current, $(T_c = 65^{\circ}C, f = 60 \text{ Hz}, \text{Time} = 1 \text{ sec})$	I _{T (RMS)}	2.0	А
Peak Non-repetitive Surge Current, @T _A = 25°C, (1/2 Cycle, Sine Wave, 60 Hz)	I _{TSM}	15	A
Circuit Fusing Considerations (t = 8.3 ms)	l²t	0.9	A2s
Forward Peak Gate Power (Pulse Width \leq 1.0 sec, T _A = 25°C)	P _{GM}	0.5	W
Forward Average Gate Power (t = 8.3 msec, $T_A = 25^{\circ}C$)	P _{GM (AV)}	0.1	W
Forward Peak Gate Current (Pulse Width \leq 1.0 s, T _A = 25°C)	I _{FGM}	0.2	А
Reverse Peak Gate Voltage (Pulse Width \leq 1.0 $\mu s, T_{_{\!\!A}}$ = 25°C)	V _{RGM}	5.0	V
Operating Junction Temperature Range @ Rated $V_{_{\rm RRM}}$ and $V_{_{\rm DRM}}$	TJ	-40 to +110	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

Thermal Characteristics					
Rating	Symbol	Value	Unit		
Thermal Resistance, Junction-to-Ambient PCB Mounted	R _{8JA}	156	mW		
Thermal Resistance, Junction–to–Tab Measured on MT2 Tab Adjacent to Epoxy	R _{BJT}	25	°C/W		
Maximum Device Temperature for Soldering Purposes for 10 Secs Maximum	TL	260	°C		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Electrical Characteristics · **OFF** ($T_J = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Forward or Reverse Blocking Current (Note 3) (V_{AK} = Rated V_{DRM} or V_{BRM} , R_{GK} = 1000 kQ	$T_{J} = 25^{\circ}C$	I _{DRM} ,	-	-	1.0	
$v_{AK} = 11000 \text{ kg}$	T _J = 110°C		-	-	200	μΑ

Electrical Characteristics - **ON** ($T_J = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Forward On-State Voltage (Note 2) ($I_{TM} = 2.2 \text{ A Peak}$)		V _{TM}	-	1.2	1.7	V
HGate Trigger Current (Note 3)	$T_c = 25^{\circ}C$		_	30	200	μA
$(V_{_{D}} = 12 \text{ V}, \text{ R}_{_{L}} = 100 \Omega, \text{ T}_{_{C}} = 25^{\circ}\text{C})$	T _c =-40°C	GT	_	-	500	
Gate Trigger Voltage (dc) (Note 3)	T _c = 25°C	V _{GT}	-	-	0.8	V
$(V_{AK} = 7 \text{ Vdc}, R_{L} = 100\Omega)$	T _c =-40°C		-	-	1.2	
Gate Non–Trigger Voltage ($V_{AK} = V_{DRM'} R_{L} = 100 \Omega$)	$T_c = 110^{\circ}C$	V _{gd}	0.1	-	-	V
Holding Current	$T_c = 25^{\circ}C$		_	2.0	5.0	V
$(V_{_{AK}} = 12 \text{ V}, \text{ R}_{_{GK}} = 1000 \Omega)$ Initiating Current = 200 mA	T _c =-40°C		_	-	10	V

Dynamic Characteristics						
Characteristic	Symbol	Min	Тур	Max	Unit	
Critical Rate-of-Rise of Off State Voltage ($T_c = 110^{\circ}C$)	dv/dt	_	25	_	V/µs	
Critical Rate of Rise of On-State Current ($T_c = 110^{\circ}C$, $I_g = 2 \times I_{gT}$, $R_{gK} = 1 \text{ k}\Omega$)		-	20	_	A/µs	

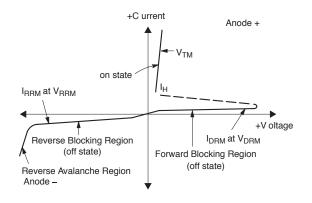
2. Pulse Width =1.0 ms, Duty Cycle \leq 1%.

3. RGK Current not included in measurement.



Voltage Current Characteristic of SCR

Symbol	Parameter
V _{drm}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current



Current Derating



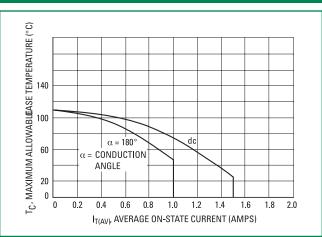


Figure 2. Maximum Ambient Temperature

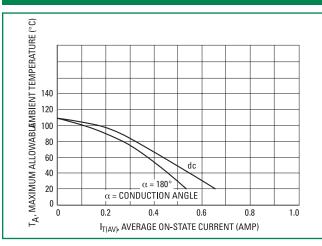


Figure 3. Typical Forward Voltage

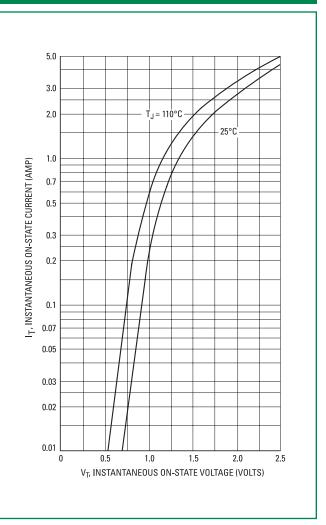
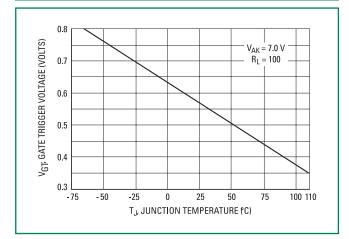




Figure 4. Thermal Response



Figure 5. Typical Gate Trigger Voltage



V_{AK} = 12 V

 $R_L = 100 \Omega$

Figure 6. Typical Gate Trigger Current

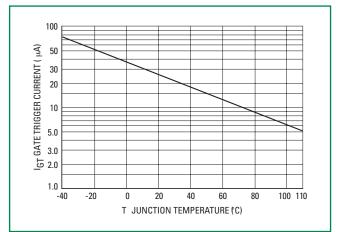
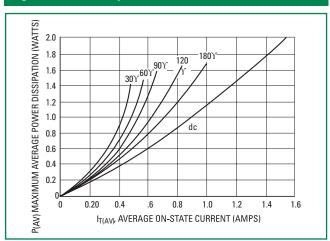


Figure 8. Power Dissipation





10

5.0

2.0

1.0 L -40

-20

0

20

40

T_J, JUNCTION TEMPERATURE №C)

6

80

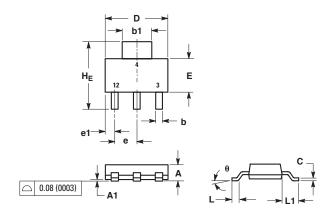
100 110

I_H , HOLDING CURRENT (mA)





Dimensions

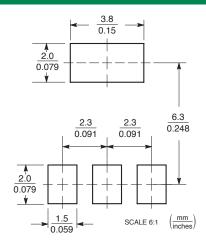


.	Inches			Millimeters		
Dim	Min	Nom	Max	Min	Nom	Max
А	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
H _E	6.70	7.00	7.30	0.264	0.276	0.287
0		-			-	

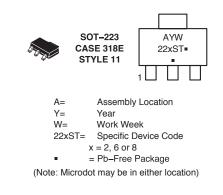
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

Soldering Footprint



Part Marking System



Pin Assignment	
1	K (Cathode)
2	A (Anode)
3	G (Gate)
4	A (Anode)

Ordering InformationDevicePackageShippingNYC222STT1GSOT-223
(Pb-Free)AppliesNYC226STT1GSOT-223
(Pb-Free)1000/Tape & ReelNYC228STT1GSOT-223
(Pb-Free)1000/Tape & Reel

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